

MG970 GaAs Hall Element

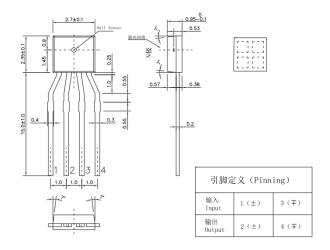
Linear GaAs Hall Element

Excellent Thermal Characteristics

Thin-type SIP Package

Shipped in Bulk by Pack (500pcs devices per pack)

Dimensional Drawing (Unit: mm)



Absolute Maximum Rating

Operating Temperature Range Storage Temperature Range Maximum Input Current Icmax

-40°C ~ 125°C -40°C ~ 150°C 11mA

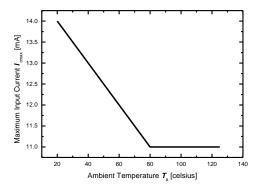


Figure 1. Maximum input current Icmax

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Electrical Characteristics (RT=25°C)

Item Symbol Test Condi. Min. Typ. Max. Unit B = 50mT, Ic=5mA Hall Voltage V_{H} 82 92 102 mV $T_a = RT$ B = 0mT, $I_C = 0.1mA$ 1000 1250 1500 Input Resist. R_{in} Ω $T_a = RT$ B = 0mT, $I_C = 0.1mA$ 1800 2500 Output Resist. **R**out 3000 Ω $T_a = RT$ B = 0mT, $I_C = 5mA$ Offset Voltage -6 +6 mV V_{os} $T_a = RT$ $B = 50 \text{mT}, I_{C} = 1 \text{mA},$ 0.06 %/°C Temp. Coeffi. of VH |α **/**⁄⊦| $T_a = 25^{\circ}C \sim 125^{\circ}C$ B = 0mT, $I_C = 0.1mA$, Temp. Coeffi. of Rin αR_{in} 0.3 %/°C $T_a = 25^{\circ}C \sim 125^{\circ}C$ **B** = 0.1 - 0.5T, **I**_C = 1mA Linearity of VH ΔK -2 +2 % $T_a = RT$

Table 1. Electrical Characteristics of MG970.

Note:

1.
$$V_{\rm H} = V_{\rm H-M} - V_{\rm os}$$

In which $V_{\text{H-M}}$ is the Output Hall Voltage, V_{H} is the Hall Voltage and V_{os} is the offset Voltage under

the identical electrical stimuli.

2.
$$\alpha V_{\rm H} = \frac{1}{V_{\rm H} (T_{a1})} \times \frac{V_{\rm H} (T_{a2}) - V_{\rm H} (T_{a1})}{T_{a2} - T_{a1}} \times 100$$

$$T_{a1} = 25$$
°C, $T_{a2} = 125$ °C

3.
$$\alpha R_{\text{in}} = \frac{1}{R_{\text{in}} (T_{a1})} \times \frac{R_{\text{in}}(T_{a2}) - R_{\text{in}} (T_{a1})}{T_{a2} - T_{a1}} \times 100$$

$$T_{a1} = 25$$
°C, $T_{a2} = 125$ °C

4.
$$\Delta K = \frac{K(B_1) - K(B_2)}{\frac{K(B_1) + K(B_2)}{2}} \times 100$$
 $K = \frac{V_H}{I_c \times B}$

$$B_1 = 0.5 \text{T}, \quad B_2 = 0.1 \text{T}$$



Characteristic Curves

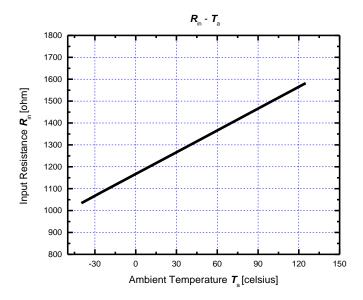


Figure 2. Input resistance R_{in} as a function of ambient temperature $T_{a.}$

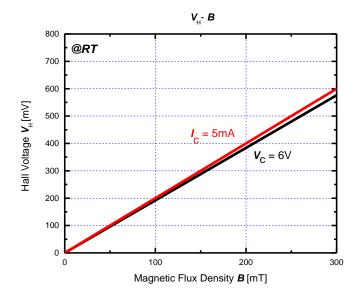


Figure 3. Hall voltage V_H as a function of magnetic flux density B.

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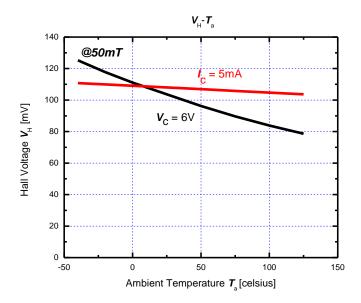


Figure 4. Hall voltage $V_{\rm H}$ as a function of ambient temperature $T_{\rm a.}$

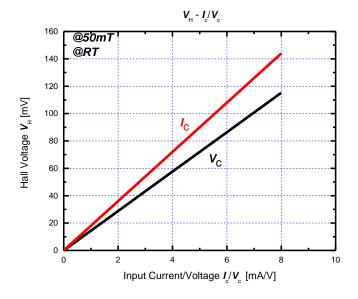


Figure 5. Hall voltage $V_{\rm H}$ as a function of electrical stimuli $I_{\rm c}/V_{\rm c.}$

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Reliability Test Terms

Table 2. Reliability Test Terms, Conditions and Duration.

No.	Terms	Conditions	Duration
1	High Temperature Storage (HTS)	【JEITA EIAJ ED-4701】 7 a =150 (0 ~ +10) °C	1000 hrs
2	Heat Cycle (HC)	[JEITA EIAJ ED-4701] $T_a = -55^{\circ}\text{C} \sim 150 ^{\circ}\text{C}$ high temp normal temp low temp. $30 \text{min} - 5 \text{min} - 30 \text{min}$	50 cycles
3	Temp. Humidity Storage (THS)	[JEITA EIAJ ED-4701] T _a =85±3 °C , R _H =85±5 %	1000 hrs
4	Resist. to Hand Soldering Heat (RHSH)	[JEITA EIAJ ED-4701] Dipped in the 300±5 °C solder up to the 1 mm part from the body	5 sec
5	High Temp. Operating (HTO)	T_a =125 °C , V_c =7.5V	1000 hrs

Criteria:

- Variation of Hall Voltage $V_{\rm H}$ and input/output resistances $\emph{R}_{\rm in/out}$ are less than 20%.
- Variation of offset voltage V_{os} is less than $\pm 16 \text{mV}$.
- Other parameters in **Table 1**. are still within their ranges stated in **Table 1**.

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Matrix Opto. Co., Ltd -MG970 GaAs Hall Element-

Soldering Conditions

The following conditions should be preserved. Solder ability should be checked by yourself, because it is depend on solder paste material and other parameters.

Material of solder flux

- Use the resin based flux and refrain from using organic or inorganic acid based and water-soluble one.

Cleansing of solder flux conditions

- Use Ethanol or Isopropyl alcohol as cleansing material.
- Process temperature should be 50 °C or less.
- Duration should be 5 minutes or less.

Hand soldering conditions

- Apart from the mold resin more than 1mm.
- Solder at temperature 300 °C for less than 5s.

Wave soldering conditions

- Temperature in Pre-heating zone should be lower than 150°C.
- Temperature in Soldering zone should be lower than 280°C.



Precautions for ESD

This product is the device that is sensitive to ESD (Electrostatic Discharge). Handling Hall Elements with the ESD-Caution mark under the environment in which

- Static electrical charge is unlikely to arise (Ex: Relative Humidity over 40%RH).
- Wearing the anti-static suit and wristband when handling the devices.
- Implementing measures against ESD as for containers that directly touch the devices.

Precautions for Storage

- Products should be stored at an appropriate temperature and humidity (5°C to 35°C, 40%RH to 60%RH) after the unsealing of the MBB. Keeping products away from chlorine and corrosive gas.
- For storage longer than 2 years

Products are sealed in MBB with a desiccant. It is recommended to store in nitrogen atmosphere with MBB sealed. Oxygen and H₂O of atmosphere oxidizes leads of products and lead solder ability get worse.

Precautions for Safety

- Do not alter the form of this product into a gas, powder or liquid through burning, crushing or chemical processing.
- Observe laws and company regulations when discarding this product.

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